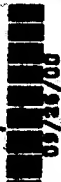


10006 U.S. PTO  
09/670520



438	Class	Subclass	ISSUE CLASSIFICATION
514			

# U.S. UTILITY Patent Application

SCANNED	I.P.E.	PATENT DATE
M.H. PD	AA	

PATENT NUMBER

APPLICATION NO. 09/670520	CONT/PRIOR F	CLASS 438	SUBCLASS 517	ART UNIT 2812 28-5	EXAMINER G Lee MSA
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APPLICANTS  
Wakako Moriyama  
Naoki Kai  
Hiroaki Hazama  
Keiki Nagai

TITLE  
Method for manufacturing semiconductor devices using thermal nitride films as gate insulating films

PTO-2040  
12/99

## ISSUING CLASSIFICATION

ORIGINAL		CROSS REFERENCE(S)							
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)						
438	514	438	517	195	201	591	593	767	
INTERNATIONAL CLASSIFICATION		257	314	331					
H01L	21/425								

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<input type="checkbox"/> <b>TERMINAL DISCLAIMER</b>  <input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.  <input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____  <input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	<b>DRAWINGS</b> Sheets Drwg. 21    Figs. Drwg. 44    Print Fig. 5F 26			<b>CLAIMS ALLOWED</b> Total Claims 15    Print Claim for O.G. 1	
	(Primary Examiner) _____ (Date) _____ (Legal Instruments Examiner) _____ (Date) _____			<b>NOTICE OF ALLOWANCE MAILED</b>  <b>ISSUE FEE</b> Amount Due _____ Date Paid _____	
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